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October 2013

FQP45N15V2 / FQPF45N15V2

N-Channel QFET® MOSFET

150 V, 45 A, 40 mΩ

Description

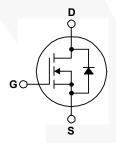
This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 45 A, 150 V, R_{DS(on)} = 40 m Ω (Max.) @ V_{GS} = 10 V, I_D = 22.5 A
- Low Gate Charge (Typ. 72 nC)
- Low Crss (Typ. 135 pF)
- · 100% Avalanche Tested







Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

Symbol	Parameter		FQP45N15V2	FQPF45N15V2	Unit
V _{DSS}	Drain-Source Voltage		150		V
I _D	Drain Current - Continuous (T _C = 25°C) - Continuous (T _C = 100°C)		45	45 *	Α
			31	31 *	Α
I _{DM}	Drain Current - Pulsed	(Note 1)	180	180 *	Α
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy (I		1124		mJ
I _{AR}	Avalanche Current	(Note 1)	45		Α
E _{AR}	Repetitive Avalanche Energy (No.		22		mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5		V/ns
P_{D}	Power Dissipation (T _C = 25°C)		220	66	W
	- Derate above 25°C		1.47	0.44	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
T _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300		°C

^{*} Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FQP45N15V2	FQPF45N15V2	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.68	2.25	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink, Typ.	0.5		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQP45N15V2	PV245N15	TO-220	Tube	N/A	N/A	50 units
FQPF45N15V2	FQPF45N15V2	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions		Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	150			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature I_D = 250 μ A, Referenced to 25°C Coefficient		-	0.21		V/°C
I _{DSS} Zero Gate Voltage D	Zana Cata Valta da Dania Cumant	Current $V_{DS} = 150 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 120 \text{ V}, T_{C} = 150 ^{\circ}\text{C}$			1	μΑ
	Zero Gate voltage Drain Current				10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Cha	racteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 22.5 A		0.034	0.04	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 22.5 A		40		S
Dynami C _{iss}	ic Characteristics	V - 25 V V - 0 V		2330	3030	pF
	<u>'</u>	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$				•
Coss	Unitout Capacitance			510	h/0	0
C _{oss}	Output Capacitance Reverse Transfer Capacitance	f = 1.0 MHz		510 135	670 176	pF pF
C _{rss} Switchi	Reverse Transfer Capacitance ng Characteristics	f = 1.0 MHz		135		рF
C _{rss} Switchi t _{d(on)}	Reverse Transfer Capacitance ing Characteristics Turn-On Delay Time	V _{DD} = 75 V, I _D = 45 A,		135		
$\begin{aligned} & & & & & \\ & & & & & \\ & & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & & $	Reverse Transfer Capacitance ing Characteristics Turn-On Delay Time Turn-On Rise Time			135 22 232	176	pF
C _{rss} Switchi t _{d(on)}	Reverse Transfer Capacitance ing Characteristics Turn-On Delay Time Turn-On Rise Time Turn-Off Delay Time	$V_{DD} = 75 \text{ V}, I_{D} = 45 \text{ A},$ $R_{G} = 25 \Omega$		135	176 54	pF
$\begin{aligned} & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & $	Reverse Transfer Capacitance ing Characteristics Turn-On Delay Time Turn-On Rise Time	V _{DD} = 75 V, I _D = 45 A,		135 22 232	176 54 474	pF ns ns
	Reverse Transfer Capacitance Ing Characteristics Turn-On Delay Time Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time Total Gate Charge	$V_{DD} = 75 \text{ V}, I_{D} = 45 \text{ A},$ $R_{G} = 25 \Omega$		22 232 224	54 474 458	pF ns ns
$\begin{aligned} & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & $	Reverse Transfer Capacitance ing Characteristics Turn-On Delay Time Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time	$V_{DD} = 75 \text{ V}, I_{D} = 45 \text{ A},$ $R_{G} = 25 \Omega$ (Note 4)	 	135 22 232 224 246	176 54 474 458 502	ns ns ns

Q_{rr}

t_{rr}

 I_{SM}

V_{SD}

Notes. The second of the seco

Drain-Source Diode Forward Voltage

Maximum Pulsed Drain-Source Diode Forward Current

Reverse Recovery Time

Reverse Recovery Charge

4. Essentially independent of operating temperature

180

176

1.19

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Α

٧

ns

μС

 $V_{GS} = 0 \text{ V, } I_{S} = 45 \text{ A}$

 $V_{GS} = 0 \text{ V, } I_{S} = 45 \text{ A,}$

 $dI_F / dt = 100 A/\mu s$

Typical Characteristics

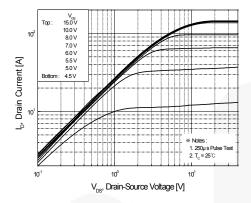


Figure 1. On-Region Characteristics

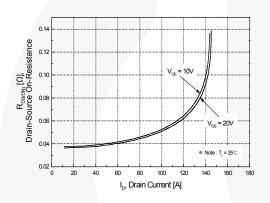


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

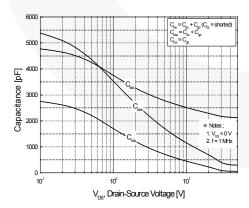


Figure 5. Capacitance Characteristics

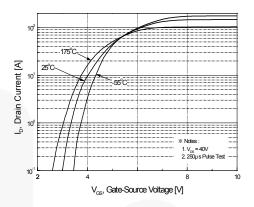


Figure 2. Transfer Characteristics

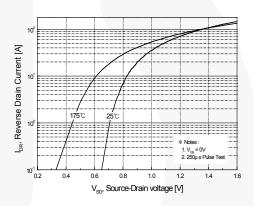


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

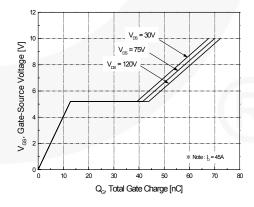


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

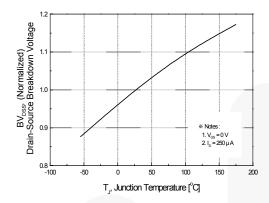


Figure 7. Breakdown Voltage Variation vs Temperature

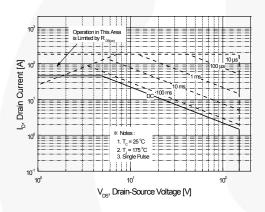


Figure 9-1. Maximum Safe Operating Area for FQP45N15V2

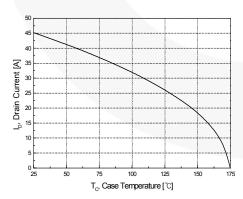


Figure 10. Maximum Drain Current vs Case Temperature

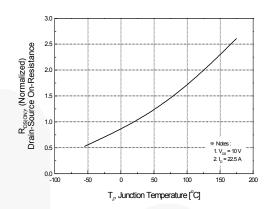


Figure 8. On-Resistance Variation vs Temperature

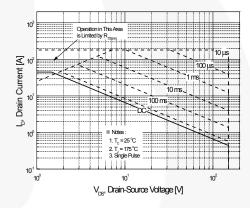


Figure 9-2. Maximum Safe Operating Area for FQPF45N15V2

Typical Characteristics (Continued)

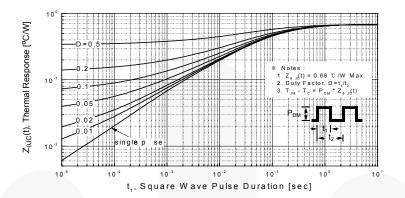


Figure 11. Transient Thermal Response Curve for FQP45N15V2

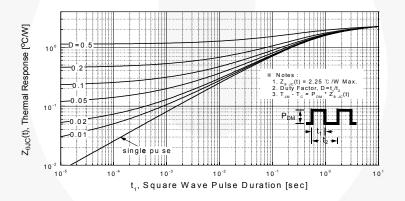


Figure 11-2. Transient Thermal Response Curve for FQPF45N15V2

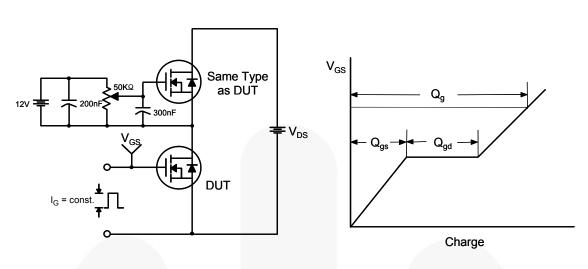


Figure 12. Gate Charge Test Circuit & Waveform

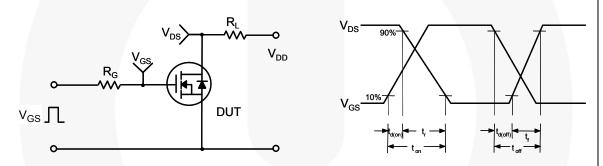


Figure 13. Resistive Switching Test Circuit & Waveforms

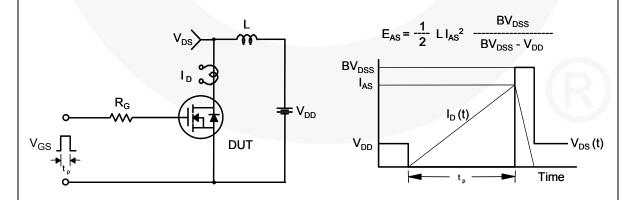
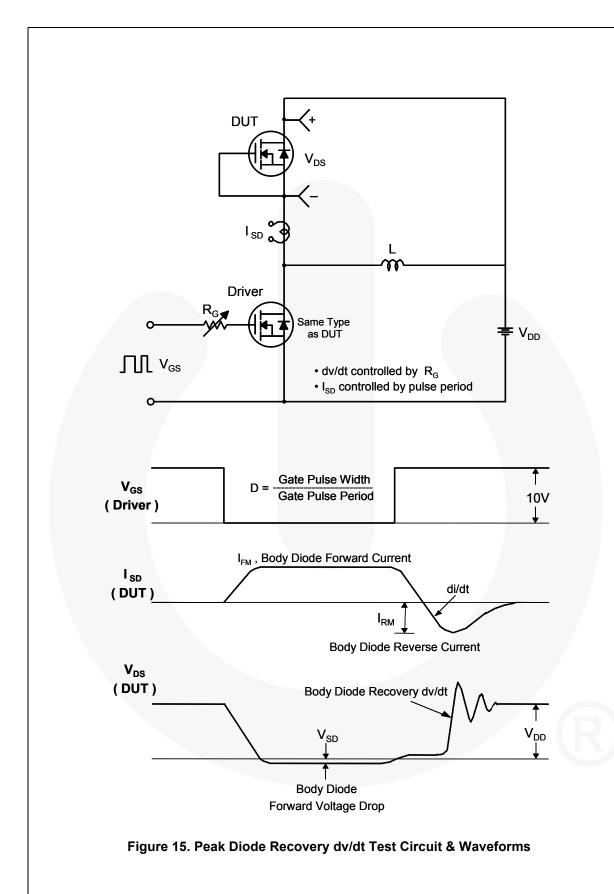


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

TO-220 3L

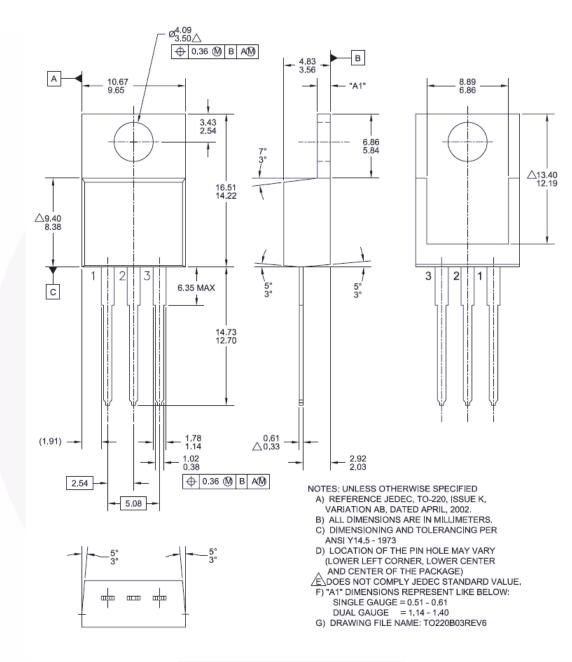


Figure 16. TO-220, Molded, 3Lead, Jedec Variation AB

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Dimension in Millimeters

Mechanical Dimensions

TO-220F 3L

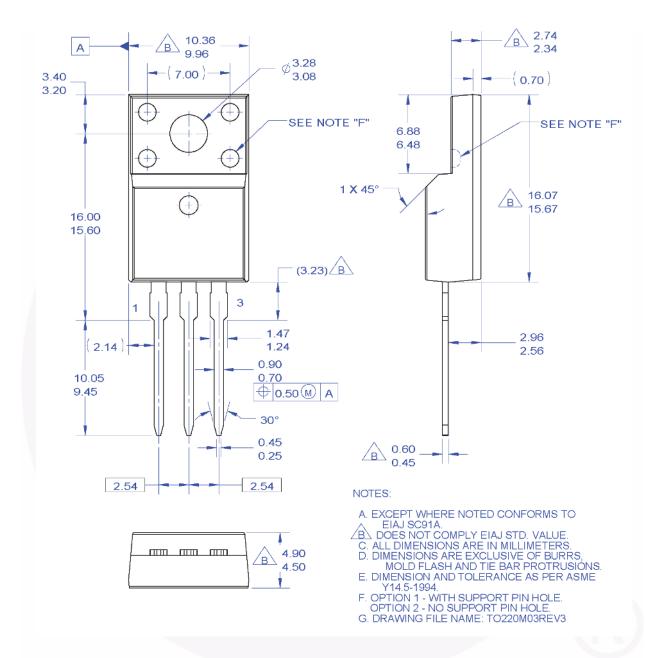


Figure 17. TO220, Molded, 3LD, Full Pack, EIAJ SC91, Straight Lead

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Dimension in Millimeters





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